# **74LVC2G38**

## Dual 2-input NAND gate; open drain

Rev. 14 — 21 June 2022

**Product data sheet** 

### 1. General description

The 74LVC2G38 is a dual 2-input NAND gate with open-drain outputs. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

### 2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant outputs for interfacing with 5 V logic
- Overvoltage tolerant inputs to 5.5 V
- · High noise immunity
- CMOS low power dissipation
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- · Complies with JEDEC standard:
- JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
  - JESD36 (4.5 V to 5.5 V)
- ESD protection:
- HBM: JESD22-A114F exceeds 2000 V
  - MM: JESD22-A115-A exceeds 200 V
- ±24 mA output drive (V<sub>CC</sub> = 3.0 V)
- · Open-drain outputs
- · Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- · Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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## 3. Ordering information

**Table 1. Ordering information** 

Type number	Package			
	Temperature range	Name	Description	Version
74LVC2G38DP	-40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2
74LVC2G38DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	<u>SOT765-1</u>
74LVC2G38GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1
74LVC2G38GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm	SOT1089
74LVC2G38GM	-40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm	SOT902-2
74LVC2G38GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	SOT1116
74LVC2G38GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203
74LVC2G38GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 × 0.8 × 0.32 mm	SOT1233-2

## 4. Marking

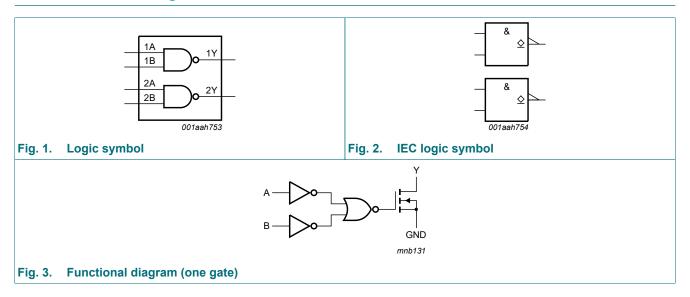
### Table 2. Marking codes

Type number	Marking code[1]
74LVC2G38DP	Y38
74LVC2G38DC	Y38
74LVC2G38GT	Y38
74LVC2G38GF	YB
74LVC2G38GM	Y38
74LVC2G38GN	YB
74LVC2G38GS	YB
74LVC2G38GX	YB

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

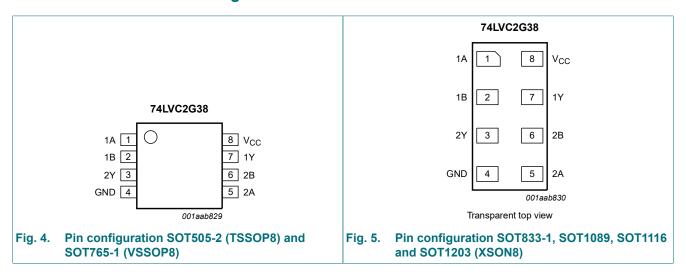
Dual 2-input NAND gate; open drain

## 5. Functional diagram



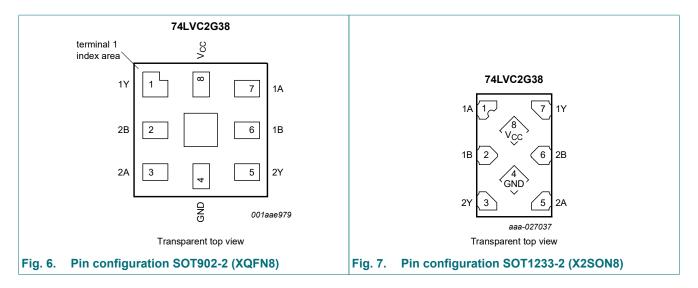
## 6. Pinning information

### 6.1. Pinning



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### 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Pin		
	SOT505-2, SOT765-1, SOT833-1, SOT1089, SOT1116, SOT1203 and SOT1233-2	SOT902-2		
1A, 2A	1, 5	7, 3	data input	
1B, 2B	2, 6	6, 2	data input	
GND	4	4	ground (0 V)	
1Y, 2Y	7, 3	1, 5	data output	
V <sub>CC</sub>	8	8	supply voltage	

## 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ Z = high-impedance \ OFF-state.$ 

Input		Output
nA	nB	nY
L	L	Z
L	Н	Z
Н	L	Z
Н	Н	L

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### 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+6.5	V
VI	input voltage		[1]	-0.5	+6.5	V
Vo	output voltage	Active mode	[1]	-0.5	V <sub>CC</sub> + 0.5	V
		Power-down mode; V <sub>CC</sub> = 0 V	[1]	-0.5	+6.5	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V		-50	-	mA
I <sub>OK</sub>	output clamping current	$V_O < 0 \text{ V or } V_O > V_{CC}$		-	±50	mA
Io	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±50	mA
I <sub>CC</sub>	supply current			-	100	mA
I <sub>GND</sub>	ground current			-100	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C				
		All packages except SOT1233-2	[2]	-	250	mW
		SOT1233-2 package	[3]	-	300	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT765-1 (VSSOP8) package: Ptot derates linearly with 4.9 mW/K above 99 °C.

For SOT833-1 (XSON8) package: Ptot derates linearly with 3.1 mW/K above 68 °C.

For SOT1089 (XSON8) package: Ptot derates linearly with 4.0 mW/K above 88 °C.

For SOT902-2 (XQFN8) packages:  $P_{tot}$  derates linearly with 4.1 mW/K above 89 °C.

For SOT1116 (XSON8) package:  $P_{tot}$  derates linearly with 4.2 mW/K above 90 °C.

For SOT1203 (XSON8) package:  $P_{tot}$  derates linearly with 3.6 mW/K above 81 °C. For SOT1233-2 (X2SON8) package:  $P_{tot}$  derates linearly with 7.7 mW/K above 118 °C.

## 9. Recommended operating conditions

**Table 6. Operating conditions** 

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		1.65	5.5	V
VI	input voltage		0	5.5	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		disable mode	0	5.5	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	5.5	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 1.65 V to 2.7 V	-	20	ns/V
		V <sub>CC</sub> = 2.7 V to 5.5 V	-	10	ns/V

<sup>[2]</sup> For SOT505-2 (TSSOP8) package: P<sub>tot</sub> derates linearly with 4.6 mW/K above 96 °C.

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### 10. Static characteristics

#### **Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T <sub>amb</sub> = -2	10 °C to +85 °C		_	1		
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.7 × V <sub>CC</sub>	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.3 × V <sub>CC</sub>	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH}$ or $V_{IL}$				
		$I_O = 100 \mu A; V_{CC} = 1.65 V \text{ to } 5.5 V$	-	-	0.1	V
		I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V	-	0.08	0.45	V
		I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V	-	0.14	0.3	V
		I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V	-	0.19	0.4	V
		I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V	-	0.37	0.55	V
		$I_{O}$ = 32 mA; $V_{CC}$ = 4.5 V	-	0.43	0.55	V
I <sub>I</sub>	input leakage current	$V_{I} = 5.5 \text{ V or GND}; V_{CC} = 0 \text{ V to } 5.5 \text{ V}$	-	±0.1	±1	μΑ
l <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	±0.1	±2	μA
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 5.5 V; V <sub>CC</sub> = 0 V	-	±0.1	±2	μΑ
I <sub>CC</sub>	supply current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 1.65 V to 5.5 V; I <sub>O</sub> = 0 A	-	0.1	4	μA
ΔI <sub>CC</sub>	additional supply current	per pin; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; V <sub>CC</sub> = 2.3 V to 5.5 V; I <sub>O</sub> = 0 A	-	5	500	μA
Cı	input capacitance		-	2.5	-	pF

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T <sub>amb</sub> = -4	10 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.7 × V <sub>CC</sub>	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.3 × V <sub>CC</sub>	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 100 μA; V <sub>CC</sub> = 1.65 V to 5.5 V	-	-	0.1	V
		I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V	-	-	0.70	V
		I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V	-	-	0.60	V
		I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V	-	-	0.80	V
		I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V	-	-	0.80	V
l <sub>l</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	-	-	±1	μA
I <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	±0.1	±2	μΑ
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 5.5 V; V <sub>CC</sub> = 0 V	-	-	±2	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 1.65 V to 5.5 V; I <sub>O</sub> = 0 A	-	-	4	μΑ
Δl <sub>CC</sub>	additional supply current	per pin; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; V <sub>CC</sub> = 2.3 V to 5.5 V; I <sub>O</sub> = 0 A	-	-	500	μΑ

<sup>[1]</sup> All typical values are measured at  $T_{amb}$  = 25 °C.

Dual 2-input NAND gate; open drain

## 11. Dynamic characteristics

#### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground 0 V); for test circuit see Fig. 9.

Symbol	Parameter	Conditions	-40	°C to +85 °	,C	-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	
t <sub>PZL</sub>	OFF-state to LOW	nA, nB to nY; see Fig. 8						
	propagation delay	V <sub>CC</sub> = 1.65 V to 1.95 V	1.2	3.0	8.6	1.2	10.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.7	1.8	4.8	0.7	6.0	ns
		V <sub>CC</sub> = 2.7 V	0.7	2.5	4.4	0.7	5.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.7	2.1	4.1	0.7	5.2	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.5	1.5	3.3	0.5	4.2	ns
t <sub>PLZ</sub>	LOW to OFF-state	nA, nB to nY; see Fig. 8						
	propagation delay	V <sub>CC</sub> = 1.65 V to 1.95 V	1.2	3.0	8.6	1.2	10.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.7	1.8	4.8	0.7	6.0	ns
		V <sub>CC</sub> = 2.7 V	0.7	2.5	4.4	0.7	5.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.7	2.1	4.1	0.7	5.2	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.5	1.5	3.3	0.5	4.2	ns
C <sub>PD</sub>	power dissipation capacitance	per gate; $V_I = GND$ to $V_{CC}$ [2]	-	5	-	-	-	pF

[1] Typical values are measured at nominal  $V_{CC}$  and at  $T_{amb}$  = 25 °C.

[2]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

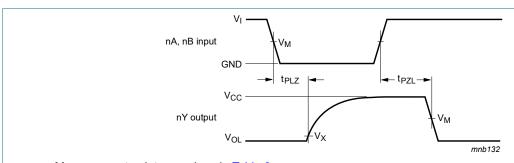
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$ 

### 11.1. Waveforms and test circuit



Measurement points are given in Table 9

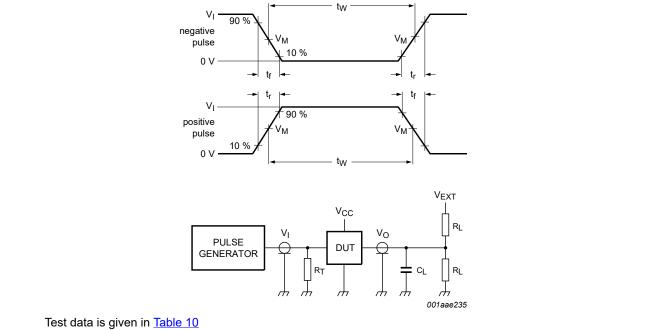
V<sub>OL</sub> is a typical output voltage level that occurs with the output load.

Fig. 8. Inputs nA and nB to output nY propagation delay times

### Dual 2-input NAND gate; open drain

**Table 9. Measurement points** 

Supply voltage	Input	Output	Output		
V <sub>CC</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>M</sub>		
1.65 V to 1.95 V	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	0.5 × V <sub>CC</sub>		
2.3 V to 2.7 V	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	0.5 × V <sub>CC</sub>		
2.7 V	1.5 V	V <sub>OL</sub> + 0.3 V	1.5 V		
3.0 V to 3.6 V	1.5 V	V <sub>OL</sub> + 0.3 V	1.5 V		
4.5 V to 5.5 V	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.3 V	0.5 × V <sub>CC</sub>		



Definitions for test circuit:

R<sub>L</sub> = Load resistance;

C<sub>L</sub> = Load capacitance including jig and probe capacitance;

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator;

 $V_{EXT}$  = External voltage for measuring switching times;

Test circuit for measuring switching times Fig. 9.

Table 10. Test data

Supply voltage	Input		Load		V <sub>EXT</sub>
V <sub>CC</sub>	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	CL	$R_L$	t <sub>PLZ</sub> , t <sub>PZL</sub>
1.65 V to 1.95 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	1 kΩ	2 × V <sub>CC</sub>
2.3 V to 2.7 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	500 Ω	2 × V <sub>CC</sub>
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	6 V
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	6 V
4.5 V to 5.5 V	V <sub>CC</sub>	≤ 2.5 ns	50 pF	500 Ω	2 × V <sub>CC</sub>

Dual 2-input NAND gate; open drain

## 12. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

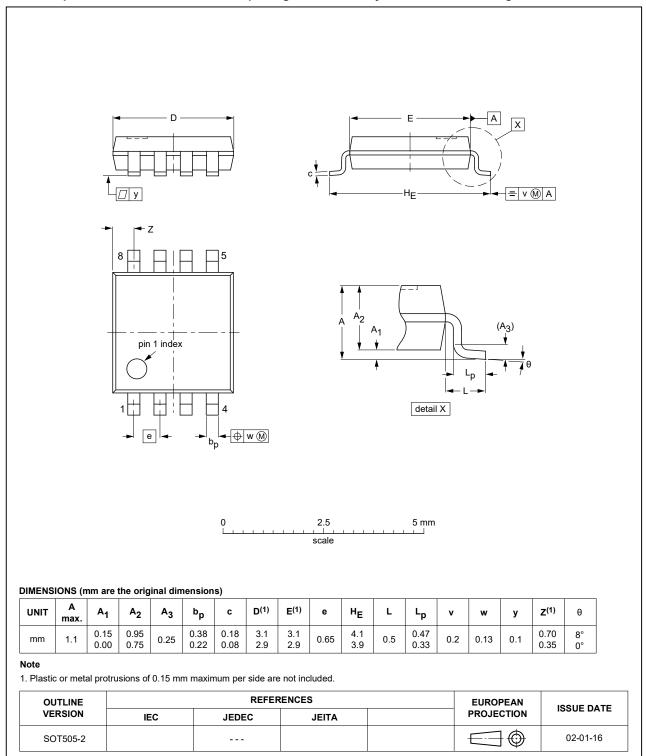


Fig. 10. Package outline SOT505-2 (TSSOP8)

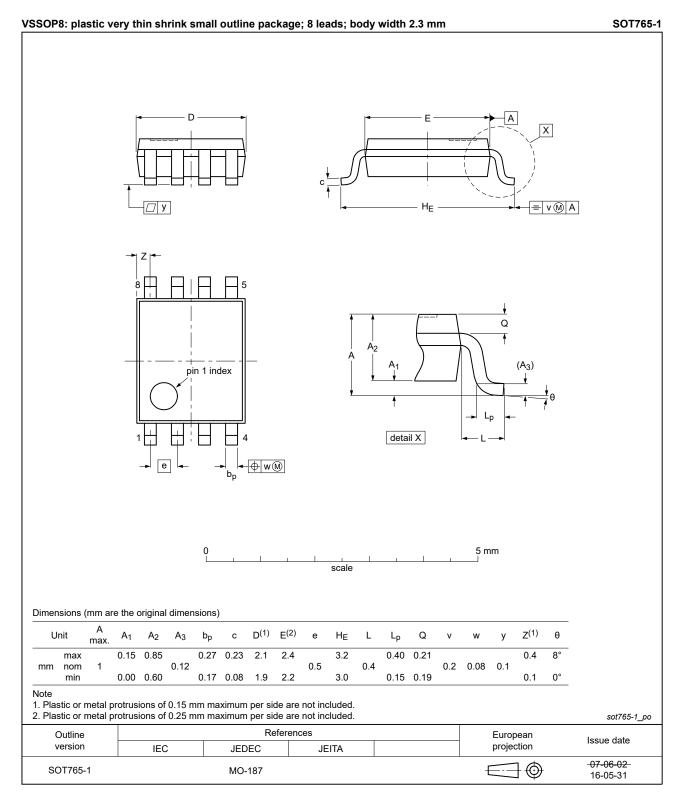


Fig. 11. Package outline SOT765-1 (VSSOP8)

Dual 2-input NAND gate; open drain

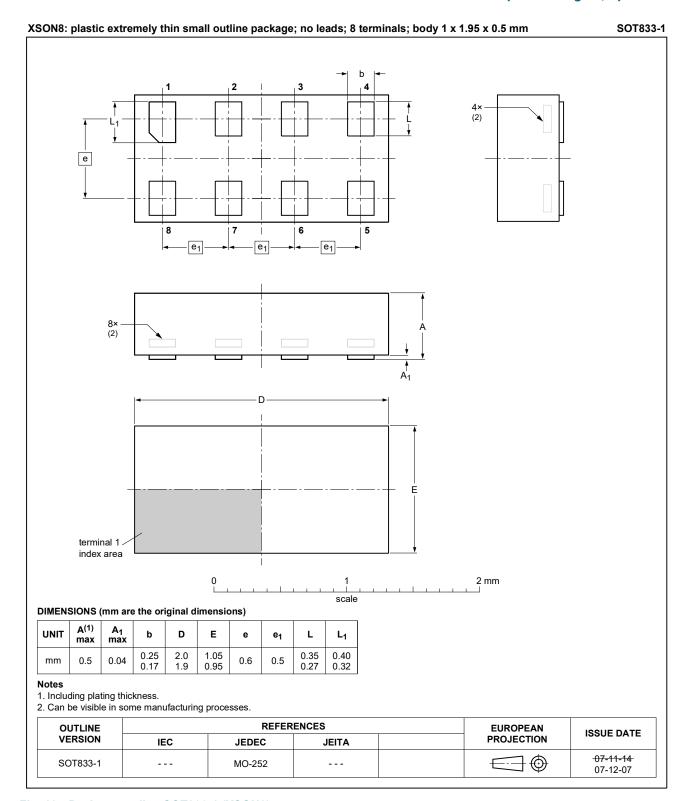


Fig. 12. Package outline SOT833-1 (XSON8)

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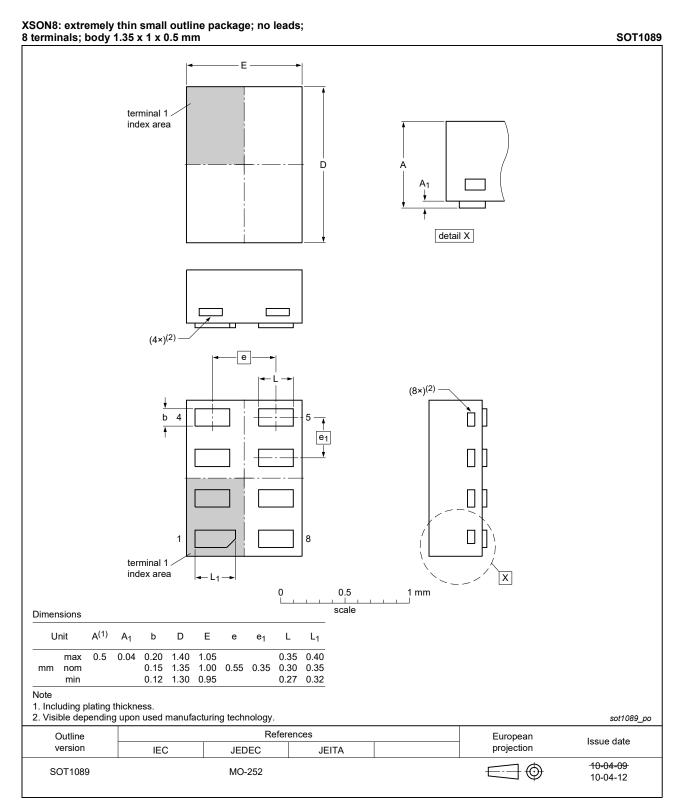


Fig. 13. Package outline SOT1089 (XSON8)

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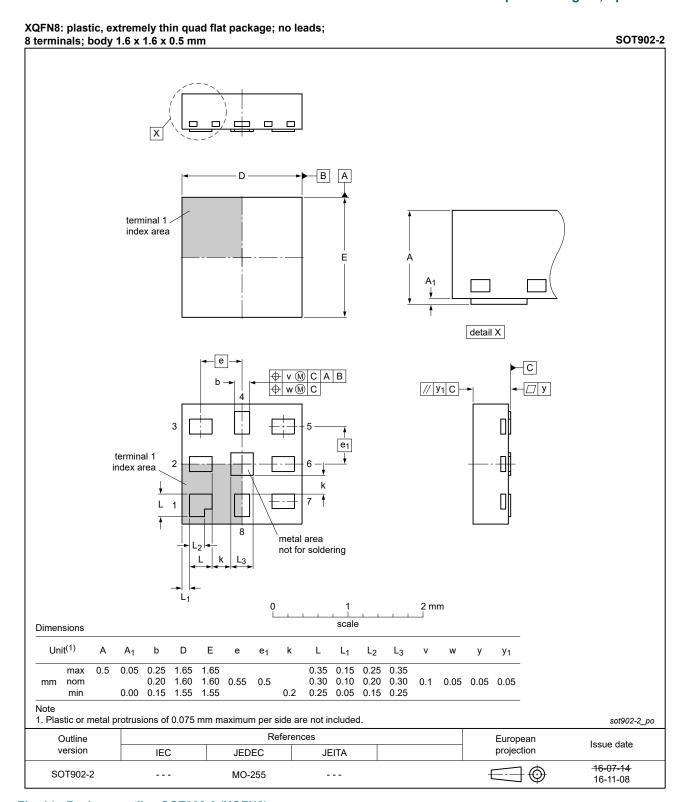


Fig. 14. Package outline SOT902-2 (XQFN8)

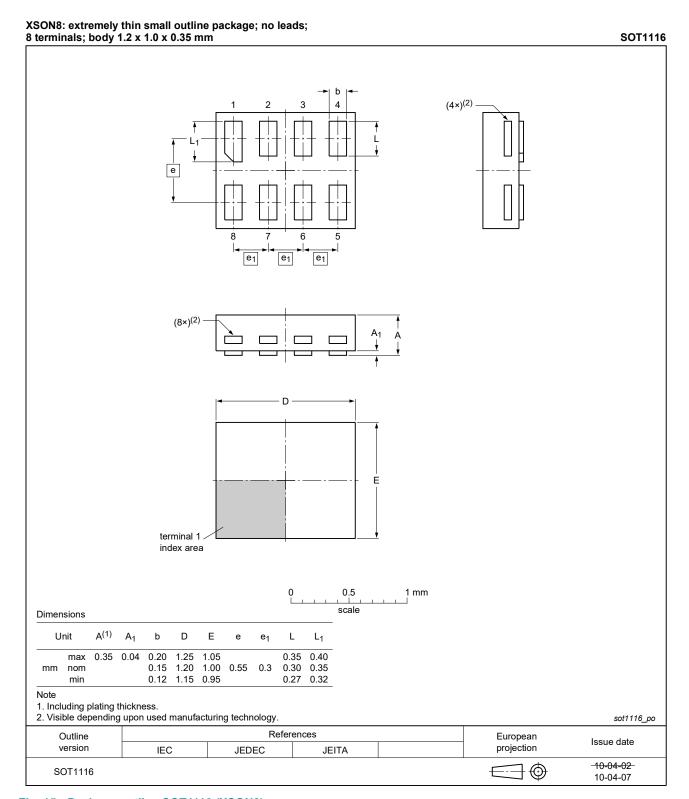


Fig. 15. Package outline SOT1116 (XSON8)

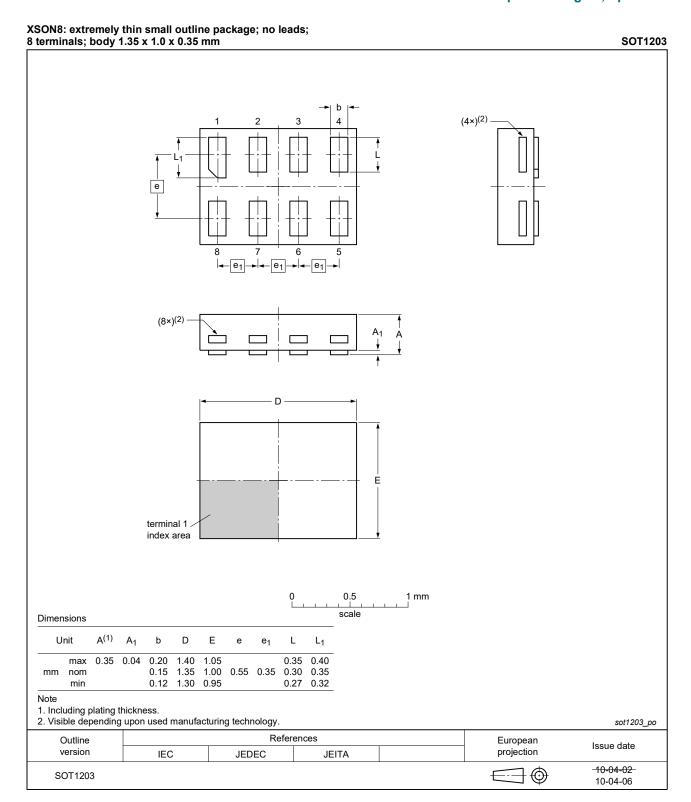


Fig. 16. Package outline SOT1203 (XSON8)

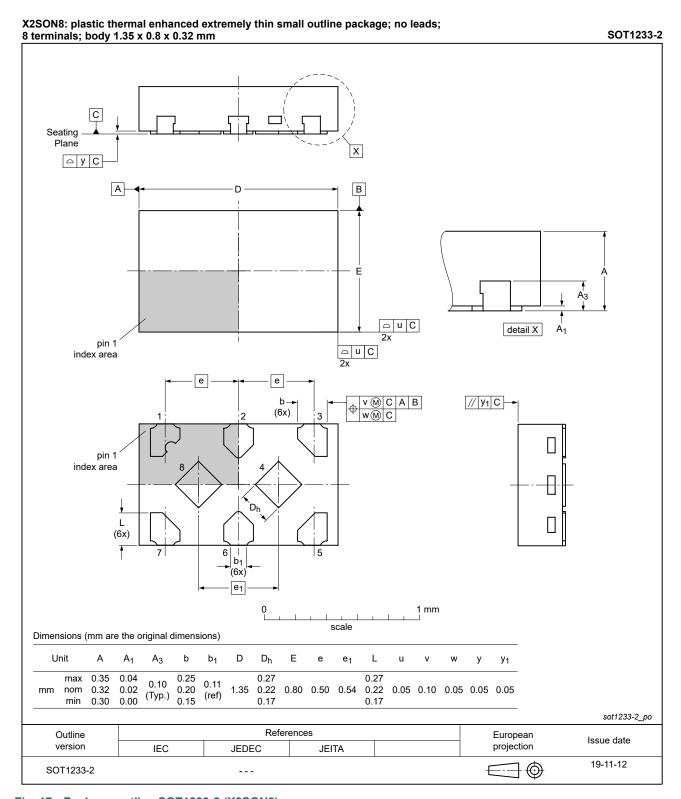


Fig. 17. Package outline SOT1233-2 (X2SON8)

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### 13. Abbreviations

#### **Table 11. Abbreviations**

Acronym	Description	
CMOS	Complementary Metal-Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
НВМ	Human Body Model	
MM	Machine Model	
TTL	Transistor-Transistor Logic	

## 14. Revision history

### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74LVC2G38 v.14	20220621	Product data sheet	-	74LVC2G38 v.13	
Modifications:	<ul> <li>Section 1 and Section 2 updated.</li> <li>SOT1233 (X2SON8) package changed to SOT1233-2 (X2SON8) package.</li> <li>Table 5: Ptot total power dissipation and derating values have been updated.</li> </ul>				
74LVC2G38 v.13	20170703	Product data sheet	-	74LVC2G38 v.12	
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Added type number 74LVC2G38GX (SOT1233 / X2SON8).</li> <li>Type number 74LVC2G38GD removed.</li> </ul>				
74LVC2G38 v.12	20161215	Product data sheet	-	74LVC2G38 v.11	
Modifications:	<u>Table 7</u> : The maximum limits for leakage current and supply current have changed.				
74LVC2G38 v.11	20130408	Product data sheet	-	74LVC2G38 v.10	
Modifications:	For type number 74LVC2G38GD XSON8U has changed to XSON8.				
74LVC2G38 v.10	20120628	Product data sheet	-	74LVC2G38 v.9	
Modifications:	For type number 74LVC2G38GM the SOT code has changed to SOT902-2.				
74LVC2G38 v.9	20111128	Product data sheet	-	74LVC2G38 v.8	
Modifications:	Legal pages updated.				
74LVC2G38 v.8	20101104	Product data sheet	-	74LVC2G38 v.7	
74LVC2G38 v.7	20090320	Product data sheet	-	74LVC2G38 v.6	
74LVC2G38 v.6	20080219	Product data sheet	-	74LVC2G38 v.5	
74LVC2G38 v.5	20070904	Product data sheet	-	74LVC2G38 v.4	
74LVC2G38 v.4	20060516	Product data sheet	-	74LVC2G38 v.3	
74LVC2G38 v.3	20050201	Product specification	-	74LVC2G38 v.2	
74LVC2G38 v.2	20041018	Product specification	-	74LVC2G38 v.1	
74LVC2G38 v.1	20031027	Product specification	-	-	

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### 15. Legal information

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Document status [1][2]	Product status [3]	Definition
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Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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